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#### APPLICATION DATA SHEET

Electronic Version v14 Stylesheet Version v14.1

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22204

\*22204\*

Application Information:

Title of Invention:

THIN FILM TRANSISTOR AND DISPLAY DEVICE, AND

METHOD FOR MANUFACTURING THEREOF

Application Type:

regular, utility

Attorney Docket Number: 740756-2993

**Botanic Information:** 

**Publication Information:** 

Suggested Figure for Publication -

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22204

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as my attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.

#### Domestic Priority Information:

This is a National Stage of JP application number PCT/JP2005/002681, filed 2005-02-15, now Pending.

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